

4-bit Single Chip Microcomputer



- Core CPU Architecture
- SVD Circuit/Comparator
- Event Counter

■ DESCRIPTION

The E0C6233 is an advanced single-chip CMOS 4-bit microcomputer consisting of the E0C6200 4-bit core CPU. It also contains the ROM, RAM, LCD driver, event counter, SVD circuit, stopwatch counter and time base counter. With wide voltage range and low power consumption, the E0C6233 provides an excellent solution for the low-power consumption systems with manganese dry cell.

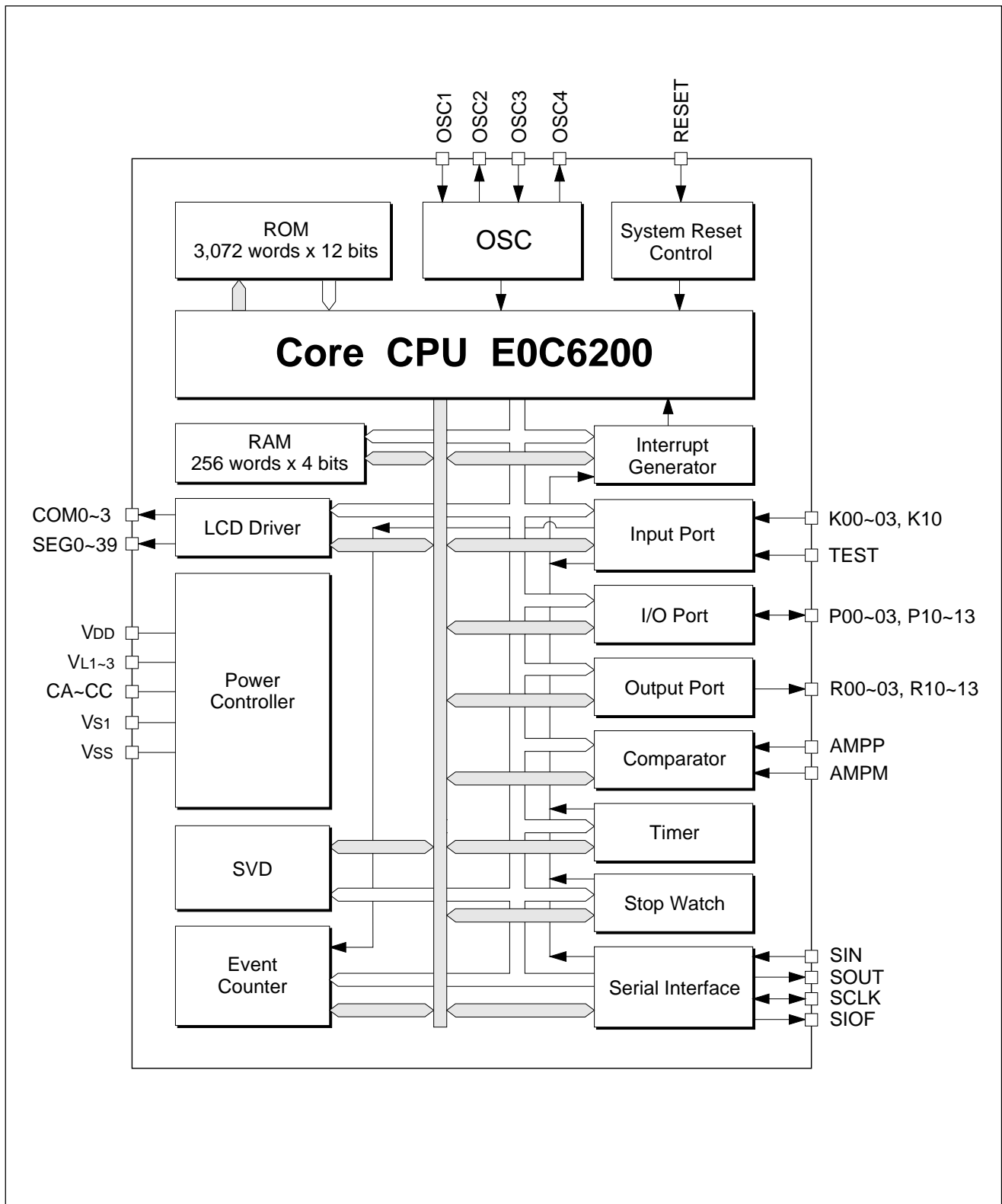
■ FEATURES

- CMOS LSI 4-bit parallel processing
- Clock 32.768kHz (Typ.)/500kHz (Typ.) (selectable by software)
- Instruction set 108 instructions
- Instruction cycle time 153μsec, 214μsec or 366μsec at 32kHz
(depending on instruction)
10μsec, 14μsec or 24μsec at 500kHz
(depending on instruction)
- ROM capacity 3,072 × 12 bits
- RAM capacity 256 × 4 bits
- Input port 5 bits (pull-down resistors are available by mask option)
- Output port 4 bits (general purpose)
2 bits (buzzer output): BZ, \overline{BZ}
1 bit (lamp output)
1 bit (clock output)
- I/O port 8 bits
- LCD driver 40 segments × 3 commons/40 segments × 4 commons
(1/3 or 1/4 duty is selectable by mask option)
- Built-in time base counter
- Built-in serial interface Clock synchronous
- Built-in stopwatch counter
- Built-in watchdog timer
- Event counter 8 lines
- Built-in AMP Operational AMP for MOS input analog comparator
- Built-in SVD 1.2 ± 0.1V/2.4 ± 0.1V (supply voltage detector)
- Interrupts External : Input interrupt 2 lines
Internal : Timer interrupt 2 lines
 Serial interface interrupt 1 line
- Current consumption E0C62L33 HALT mode (32kHz) : 1.0μA (Typ.)
 E0C6233 HALT mode (32kHz) : 1.5μA (Typ.)
 E0C62A33 HALT mode (32kHz) : 2.0μA (Typ.)
 OPERATING mode (500kHz) : 135μA (Typ.)
- Package QFP5-100pin (plastic)
Die form

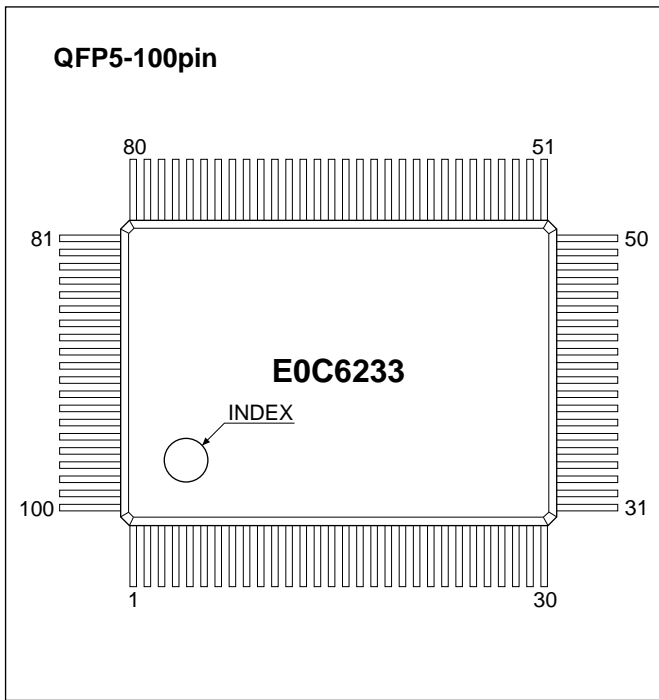
■ LINE UP

Model	Supply voltage	Clock
E0C62L33	1.5V (0.9V to 1.7V)	32kHz (Crystal oscillation)
E0C6233	3.0V (1.8V to 3.5V)	32kHz (Crystal oscillation)
E0C62A33	3.0V (2.2V to 3.5V)	32kHz (Crystal oscillation) & 500kHz (Ceramic or CR oscillation)

■ BLOCK DIAGRAM



■ PIN CONFIGURATION



No.	Pin name	No.	Pin name	No.	Pin name	No.	Pin name
1	N.C.	26	SEG38	51	N.C.	76	SIOF
2	N.C.	27	SEG39	52	N.C.	77	SCLK
3	TEST	28	N.C.	53	N.C.	78	N.C.
4	N.C.	29	AMPP	54	N.C.	79	N.C.
5	N.C.	30	N.C.	55	R11	80	N.C.
6	SEG18	31	AMPM	56	R10	81	SOUT
7	SEG19	32	K10	57	R13	82	SIN
8	SEG20	33	K03	58	Vss	83	SEG0
9	SEG21	34	K02	59	RESET	84	SEG1
10	SEG22	35	K01	60	OSC4	85	SEG2
11	SEG23	36	K00	61	OSC3	86	SEG3
12	SEG24	37	P03	62	Vs1	87	SEG4
13	SEG25	38	P02	63	OSC2	88	SEG5
14	SEG26	39	P01	64	OSC1	89	SEG6
15	SEG27	40	P00	65	VDD	90	SEG7
16	SEG28	41	P13	66	VL3	91	SEG8
17	SEG29	42	P12	67	VL2	92	SEG9
18	SEG30	43	P11	68	VL1	93	SEG10
19	SEG31	44	P10	69	CC	94	SEG11
20	SEG32	45	R03	70	CB	95	SEG12
21	SEG33	46	R02	71	CA	96	SEG13
22	SEG34	47	N.C.	72	COM3	97	SEG14
23	SEG35	48	R01	73	COM2	98	SEG15
24	SEG36	49	R00	74	COM1	99	SEG16
25	SEG37	50	R12	75	COM0	100	SEG17

N.C. = No Connection

■ PIN DESCRIPTION

Pin name	Pin No.	In/Out	Function
VDD	65	I	Power source (+) terminal
VSS	58	I	Power source (-) terminal
Vs1	62	O	Oscillation and internal logic system regulated voltage output terminal
VL1	68	O	LCD system regulated voltage output terminal (approx. -1.05 V)
VL2	67	O	LCD system booster output terminal (VL1 x 2)
VL3	66	O	LCD system booster output terminal (VL1 x 3)
CA-CC	69-71	-	Booster capacitor connecting terminal
OSC1	64	I	Crystal oscillation input terminal
OSC2	63	O	Crystal oscillation output terminal
OSC3	61	I	Ceramic or CR oscillation input terminal (Switchable by mask option, 62A33 only)
OSC4	60	O	Ceramic or CR oscillation output terminal (Switchable by mask option, 62A33 only)
K00-K03, K10	32-36	I	Input terminal
P00-P03, P10-P13	37-44	I/O	I/O terminal
R00-R03	45, 46, 48, 49	O	Output terminal
R10	56	O	Output terminal (DC or BZ output may be selected by mask option)
R13	57	O	Output terminal (DC or BZ output may be selected by mask option)
R11	55	O	Output terminal
R12	50	O	Output terminal (DC or FOUT output may be selected by mask option)
AMPP	29	I	Analog comparator non-inverted input terminal
AMPM	31	I	Analog comparator inverted input terminal
SEG0-39	6-27, 83-100	O	LCD segment output terminal (Convertible to DC output by mask option)
COM0-3	72-75	O	LCD common output terminal
SIN	82	I	Serial interface input terminal
SOUT	81	O	Serial interface output terminal
SCLK	77	I/O	Serial interface clock input/output terminal
SIOF	76	O	Serial interface status output terminal
RESET	59	I	Initial reset input terminal
TEST	3	I	Test input terminal

■ ELECTRICAL CHARACTERISTICS

● Absolute Maximum Ratings

E0C6233/62A33

(V_{DD}=0V)

Rating	Symbol	Value	Unit
Supply voltage	V _{SS}	-5.0 to 0.5	V
Input voltage (1)	V _I	V _{SS} - 0.3 to 0.5	V
Input voltage (2)	V _{Iosc}	V _{S1} - 0.3 to 0.5	V
Permissible total output current *1	ΣI _{VSS}	10	mA
Operating temperature	T _{opr}	-20 to 70	°C
Storage temperature	T _{stg}	-65 to 150	°C
Soldering temperature / Time	T _{sol}	260°C, 10sec (lead section)	—
Permissible dissipation *2	P _D	250	mW

*1: The permissible total output current is the sum total of the current (average current) that simultaneously flows from the output pins (or is draw in).

*2: In case of plastic package (QFP5-100pin).

E0C62L33

(V_{DD}=0V)

Rating	Symbol	Value	Unit
Supply voltage	V _{SS}	-2.0 to 0.5	V
Input voltage (1)	V _I	V _{SS} - 0.3 to 0.5	V
Input voltage (2)	V _{Iosc}	V _{S1} - 0.3 to 0.5	V
Permissible total output current *1	ΣI _{VSS}	10	mA
Operating temperature	T _{opr}	-20 to 70	°C
Storage temperature	T _{stg}	-65 to 150	°C
Soldering temperature / Time	T _{sol}	260°C, 10sec (lead section)	—
Permissible dissipation *2	P _D	250	mW

*1: The permissible total output current is the sum total of the current (average current) that simultaneously flows from the output pins (or is draw in).

*2: In case of plastic package (QFP5-100pin).

● Recommended Operating Conditions

E0C6233

(T_a=-20 to 70°C)

Condition	Symbol	Remark	Min.	Typ.	Max.	Unit
Supply voltage	V _{SS}	V _{DD} =0V	-3.5	-3.0	-1.8	V
Oscillation frequency	fosc1		—	32.768	—	kHz

E0C62L33

(T_a=-20 to 70°C)

Condition	Symbol	Remark	Min.	Typ.	Max.	Unit
Supply voltage	V _{SS}	V _{DD} =0V	-1.7	-1.5	-1.1	V
		V _{DD} =0V, With software control *1	-1.7	-1.5	-0.9 *2	V
		V _{DD} =0V, When the analog comparator is used	-1.7	-1.5	-1.2	V
Oscillation frequency	fosc1		—	32.768	—	kHz

*1: When switching to heavy load protection mode. Note, however, that the ON time for SVD in the heavy load protection must be limited to 10 msec per second of operation time.

*2: The possibility of LCD panel display differs depending on the characteristics of the LCD panel.

E0C62A33

(T_a=-20 to 70°C)

Condition	Symbol	Remark	Min.	Typ.	Max.	Unit
Supply voltage	V _{SS}	V _{DD} =0V	-3.5	-3.0	-2.2	V
Oscillation frequency (1)	fosc1		—	32.768	—	kHz
Oscillation frequency (2)	fosc3	duty 50±5%	50	500	600	kHz

● DC Characteristics

E0C6233/62A33

(Unless otherwise specified: V_{DD}=0V, V_{SS}=-3.0V, f_{osc1}=32.768kHz, T_a=25°C, V_{S1}/V_{L1}-V_{L3} are internal voltage, C₁-C₆=0.1μF)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
High level input voltage (1)	V _{IH1}	K00-03, K10, P00-03, P10-13 SIN, SCLK	0.2•V _{SS}		0	V
High level input voltage (2)	V _{IH2}	RESET, TEST	0.1•V _{SS}		0	V
Low level input voltage (1)	V _{IL1}	K00-03, K10, P00-03, P10-13 SIN, SCLK	V _{SS}		0.8•V _{SS}	V
Low level input voltage (2)	V _{IL2}	RESET, TEST	V _{SS}		0.9•V _{SS}	V
High level input current (1)	I _{IH1}	V _{IH1} =0V No pull down resistor	0		0.5	μA
High level input current (2)	I _{IH2}	V _{IH2} =0V With pull down resistor	4		16	μA
High level input current (3)	I _{IH3}	V _{IH3} =0V With pull down resistor	25		100	μA
Low level input current	I _{IL}	V _{IL} =V _{SS}	-0.5		0	μA
High level output current (1)	I _{OH1}	V _{OH1} =0.1•V _{SS}			-1.8	mA
High level output current (2)	I _{OH2}	V _{OH2} =0.1•V _{SS}			-0.9	mA
Low level output current (1)	I _{OL1}	V _{OL1} =0.9•V _{SS}	6.0			mA
Low level output current (2)	I _{OL2}	V _{OL2} =0.9•V _{SS}	3.0			mA
Common output current	I _{OH3}	V _{OH3} =-0.05V			-3	μA
	I _{OL3}	V _{OL3} =V _{L3} +0.05V	3			μA
Segment output current (during LCD output)	I _{OH4}	V _{OH4} =-0.05V			-3	μA
	I _{OL4}	V _{OL4} =V _{L3} +0.05V	3			μA
Segment output current (during DC output)	I _{OH5}	V _{OH5} =0.1•V _{SS}			-200	μA
	I _{OL5}	V _{OL5} =0.9•V _{SS}	200			μA

E0C62L33

(Unless otherwise specified: V_{DD}=0V, V_{SS}=-1.5V, f_{osc1}=32.768kHz, T_a=25°C, V_{S1}/V_{L1}-V_{L3} are internal voltage, C₁-C₆=0.1μF)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
High level input voltage (1)	V _{IH1}	K00-03, K10, P00-03, P10-13 SIN, SCLK	0.2•V _{SS}		0	V
High level input voltage (2)	V _{IH2}	RESET, TEST	0.1•V _{SS}		0	V
Low level input voltage (1)	V _{IL1}	K00-03, K10, P00-03, P10-13 SIN, SCLK	V _{SS}		0.8•V _{SS}	V
Low level input voltage (2)	V _{IL2}	RESET, TEST	V _{SS}		0.9•V _{SS}	V
High level input current (1)	I _{IH1}	V _{IH1} =0V No pull down resistor	0		0.5	μA
High level input current (2)	I _{IH2}	V _{IH2} =0V With pull down resistor	2		10	μA
High level input current (3)	I _{IH3}	V _{IH3} =0V With pull down resistor	12		60	μA
Low level input current	I _{IL}	V _{IL} =V _{SS}	-0.5		0	μA
High level output current (1)	I _{OH1}	V _{OH1} =0.1•V _{SS}			-300	μA
High level output current (2)	I _{OH2}	V _{OH2} =0.1•V _{SS}			-150	μA
Low level output current (1)	I _{OL1}	V _{OL1} =0.9•V _{SS}	1,400			μA
Low level output current (2)	I _{OL2}	V _{OL2} =0.9•V _{SS}	700			μA
Common output current	I _{OH3}	V _{OH3} =-0.05V			-3	μA
	I _{OL3}	V _{OL3} =V _{L3} +0.05V	3			μA
Segment output current (during LCD output)	I _{OH4}	V _{OH4} =-0.05V			-3	μA
	I _{OL4}	V _{OL4} =V _{L3} +0.05V	3			μA
Segment output current (during DC output)	I _{OH5}	V _{OH5} =0.1•V _{SS}			-100	μA
	I _{OL5}	V _{OL5} =0.9•V _{SS}	100			μA

● Analog Circuit Characteristics and Current Consumption

E0C6233 (Normal Mode)

(Unless otherwise specified: VDD=0V, VSS=-3.0V, fOSC1=32.768kHz, Ta=25°C, CG=25pF, VS1/VL1-VL3 are internal voltage, C1-C6=0.1μF)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Internal voltage	VL1	Connect 1MΩ load resistor between VDD and VL1 (without panel load)	-1.15	-1.05	-0.95	V
	VL2	Connect 1MΩ load resistor between VDD and VL2 (without panel load)	2•VL1 -0.1		2•VL1 ×0.9	V
	VL3	Connect 1MΩ load resistor between VDD and VL3 (without panel load)	3•VL1 -0.1		3•VL1 ×0.9	V
SVD voltage	VSVD		-2.55	-2.40	-2.25	V
SVD circuit response time	tSVD				100	μS
Analog comparator input voltage	VIP	Noninverted input (AMPP)	VSS+0.3		VDD-0.9	V
	VIM	Inverted input (AMPM)				
Analog comparator offset voltage	VOF				10	mV
Analog comparator response time	tAMP	VIP=-1.5V, VIM=VIP±15mV			3	mS
Current consumption	IOP	During HALT	Without panel load	1.5	4.0	μA
		During operation *1		6.0	10.0	μA

*1: The SVD circuit and analog comparator are in the OFF status.

E0C6233 (Heavy Load Protection Mode)

(Unless otherwise specified: VDD=0V, VSS=-3.0V, fOSC1=32.768kHz, Ta=25°C, CG=25pF, VS1/VL1-VL3 are internal voltage, C1-C6=0.1μF)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Internal voltage	VL1	Connect 1MΩ load resistor between VDD and VL1 (without panel load)	-1.15	-1.05	-0.95	V
	VL2	Connect 1MΩ load resistor between VDD and VL2 (without panel load)	2•VL1 -0.1		2•VL1 ×0.9	V
	VL3	Connect 1MΩ load resistor between VDD and VL3 (without panel load)	3•VL1 -0.1		3•VL1 ×0.9	V
SVD voltage	VSVD		-2.55	-2.40	-2.25	V
SVD circuit response time	tSVD				100	μS
Analog comparator input voltage	VIP	Noninverted input (AMPP)	VSS+0.3		VDD-0.9	V
	VIM	Inverted input (AMPM)				
Analog comparator offset voltage	VOF				10	mV
Analog comparator response time	tAMP	VIP=-1.5V, VIM=VIP±15mV			3	mS
Current consumption	IOP	During HALT	Without panel load	11.2	34.0	μA
		During operation *1		14.5	40.0	μA

*1: The SVD circuit is in the ON status (HVLD="1", SVDON="0"). The analog comparator is in the OFF status.

E0C62L33 (Normal Mode)

(Unless otherwise specified: VDD=0V, VSS=-1.5V, fOSC1=32.768kHz, Ta=25°C, CG=25pF, VS1/VL1-VL3 are internal voltage, C1-C6=0.1μF)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Internal voltage	VL1	Connect 1MΩ load resistor between VDD and VL1 (without panel load)	-1.15	-1.05	-0.95	V
	VL2	Connect 1MΩ load resistor between VDD and VL2 (without panel load)	2•VL1 -0.1		2•VL1 ×0.9	V
	VL3	Connect 1MΩ load resistor between VDD and VL3 (without panel load)	3•VL1 -0.1		3•VL1 ×0.9	V
SVD voltage	VSVD		-1.30	-1.20	-1.10	V
SVD circuit response time	tSVD				100	μS
Analog comparator input voltage	VIP	Noninverted input (AMPP)	VSS+0.3		VDD-0.9	V
	VIM	Inverted input (AMPM)				
Analog comparator offset voltage	VOF				20	mV
Analog comparator response time	tAMP	VIP=-1.1V, VIM=VIP±30mV			3	mS
Current consumption	IOP	During HALT	Without panel load	1.0	3.0	μA
		During operation *1		3.0	8.0	μA

*1: The SVD circuit and analog comparator are in the OFF status.

E0C62L33 (Heavy Load Protection Mode)

(Unless otherwise specified: VDD=0V, VSS=-1.5V, fosc1=32.768kHz, Ta=25°C, CG=25pF, VS1/VL1-VL3 are internal voltage, C1-C6=0.1μF)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Internal voltage	VL1	Connect 1MΩ load resistor between VDD and VL1 (without panel load)	-1.15	-1.05	-0.95	V
	VL2	Connect 1MΩ load resistor between VDD and VL2 (without panel load)	2•VL1 -0.1		2•VL1 ×0.85	V
	VL3	Connect 1MΩ load resistor between VDD and VL3 (without panel load)	3•VL1 -0.1		3•VL1 ×0.85	V
SVD voltage	VSVD		-1.30	-1.20	-1.10	V
SVD circuit response time	tsVD				100	μS
Analog comparator input voltage	VIP	Noninverted input (AMPP)	VSS+0.3		VDD-0.9	V
	VIM	Inverted input (AMPM)				
Analog comparator offset voltage	VOF				20	mV
Analog comparator response time	tAMP	VIP=-1.1V, VIM=VIP±30mV			3	mS
Current consumption	IOP	During HALT *1		2.0	7.0	μA
		During operation *1	Without panel load	8.0	18.0	μA

*1: The SVD circuit is in the ON status (HVL D="1", SVDON="0"). The analog comparator is in the OFF status.

E0C62A33 (Normal Mode)

(Unless otherwise specified: VDD=0V, VSS=-3.0V, fosc1=32.768kHz, Ta=25°C, CG=25pF, VS1/VL1-VL3 are internal voltage, C1-C6=0.1μF)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Internal voltage	VL1	Connect 1MΩ load resistor between VDD and VL1 (without panel load)	-1.15	-1.05	-0.95	V
	VL2	Connect 1MΩ load resistor between VDD and VL2 (without panel load)	2•VL1 -0.1		2•VL1 ×0.9	V
	VL3	Connect 1MΩ load resistor between VDD and VL3 (without panel load)	3•VL1 -0.1		3•VL1 ×0.9	V
SVD voltage	VSVD		-2.55	-2.40	-2.25	V
SVD circuit response time	tsVD				100	μS
Analog comparator input voltage	VIP	Noninverted input (AMPP)	VSS+0.3		VDD-0.9	V
	VIM	Inverted input (AMPM)				
Analog comparator offset voltage	VOF				10	mV
Analog comparator response time	tAMP	VIP=-1.5V, VIM=VIP±15mV			3	mS
Current consumption	IOP	During HALT	Without panel load OSCC="0"	2.0	5.0	μA
		During operation at 32kHz *1		8.0	15.0	μA
		During operation at 500kHz *1		135	300	μA

*1: The SVD circuit and analog comparator are in the OFF status.

E0C62A33 (Heavy Load Protection Mode)

(Unless otherwise specified: VDD=0V, VSS=-3.0V, fosc1=32.768kHz, Ta=25°C, CG=25pF, VS1/VL1-VL3 are internal voltage, C1-C6=0.1μF)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Internal voltage	VL1	Connect 1MΩ load resistor between VDD and VL1 (without panel load)	-1.15	-1.05	-0.95	V
	VL2	Connect 1MΩ load resistor between VDD and VL2 (without panel load)	2•VL1 -0.1		2•VL1 ×0.9	V
	VL3	Connect 1MΩ load resistor between VDD and VL3 (without panel load)	3•VL1 -0.1		3•VL1 ×0.9	V
SVD voltage	VSVD		-2.55	-2.40	-2.25	V
SVD circuit response time	tsVD				100	μS
Analog comparator input voltage	VIP	Noninverted input (AMPP)	VSS+0.3		VDD-0.9	V
	VIM	Inverted input (AMPM)				
Analog comparator offset voltage	VOF				10	mV
Analog comparator response time	tAMP	VIP=-1.5V, VIM=VIP±15mV			3	mS
Current consumption	IOP	During HALT	Without panel load OSCC="0"	11.5	35.0	μA
		During operation at 32kHz *1		16.0	45.0	μA
		During operation at 500kHz *1		130	330	μA

*1: The SVD circuit is in the ON status (HVL D="1", SVDON="0"). The analog comparator is in the OFF status.

● Oscillation Characteristics

The oscillation characteristics change depending on the conditions (components used, board pattern, etc.). Use the following characteristics as reference values.

E0C6233 (Crystal oscillation circuit)

(Unless otherwise specified: V_{DD}=0V, V_{SS}=-3.0V, Crystal: C-002R (C_I=35kΩ), C_G=25pF, C_D=built-in, T_a=25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation start voltage	V _{sta}	t _{sta} ≤5sec (V _{SS})	-1.8			V
Oscillation stop voltage	V _{stp}	t _{stp} ≤10sec (V _{SS})	-1.8			V
Built-in capacitance (drain)	C _D	Including the parasitic capacity inside the IC		18		pF
Frequency/voltage deviation	∂f/∂V	V _{SS} =-1.8 to -3.5V			5	ppm
Frequency/IC deviation	∂f/∂IC		-10		10	ppm
Frequency adjustment range	∂f/∂C _G	C _G =5 to 25pF	35	45		ppm
Harmonic oscillation start voltage	V _{hho}	(V _{SS})			-3.5	V
Permitted leak resistance	R _{leak}	Between OSC1 and V _{DD} , V _{SS}	200			MΩ

E0C62L33 (Crystal oscillation circuit)

(Unless otherwise specified: V_{DD}=0V, V_{SS}=-1.5V, Crystal: C-002R (C_I=35kΩ), C_G=25pF, C_D=built-in, T_a=25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation start voltage	V _{sta}	t _{sta} ≤5sec (V _{SS})	-1.1			V
Oscillation stop voltage	V _{stp}	t _{stp} ≤10sec (V _{SS})	-1.1(-0.9)*1			V
Built-in capacitance (drain)	C _D	Including the parasitic capacity inside the IC		18		pF
Frequency/voltage deviation	∂f/∂V	V _{SS} =-1.1 to -1.7V (-0.9) *1			5	ppm
Frequency/IC deviation	∂f/∂IC		-10		10	ppm
Frequency adjustment range	∂f/∂C _G	C _G =5 to 25pF	35	45		ppm
Harmonic oscillation start voltage	V _{hho}	(V _{SS})			-1.7	V
Permitted leak resistance	R _{leak}	Between OSC1 and V _{DD} , V _{SS}	200			MΩ

*1: Items enclosed in parentheses () are those used when operating at heavy load protection mode.

Note, however, that the ON time for SVD must be limited to 10 msec per second of operation time.

E0C62A33 (Crystal oscillation circuit)

(Unless otherwise specified: V_{DD}=0V, V_{SS}=-3.0V, Crystal: C-002R (C_I=35kΩ), C_G=25pF, C_D=built-in, T_a=25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation start voltage	V _{sta}	t _{sta} ≤5sec (V _{SS})	-2.2			V
Oscillation stop voltage	V _{stp}	t _{stp} ≤10sec (V _{SS})	-2.2			V
Built-in capacitance (drain)	C _D	Including the parasitic capacity inside the IC		18		pF
Frequency/voltage deviation	∂f/∂V	V _{SS} =-2.2 to -3.5V			5	ppm
Frequency/IC deviation	∂f/∂IC		-10		10	ppm
Frequency adjustment range	∂f/∂C _G	C _G =5 to 25pF	35	45		ppm
Harmonic oscillation start voltage	V _{hho}	(V _{SS})			-3.5	V
Permitted leak resistance	R _{leak}	Between OSC1 and V _{DD} , V _{SS}	200			MΩ

E0C62A33 (CR oscillation circuit)

(Unless otherwise specified: V_{DD}=0V, V_{SS}=-3.0V, R_{CR}=82kΩ, T_a=25°C)

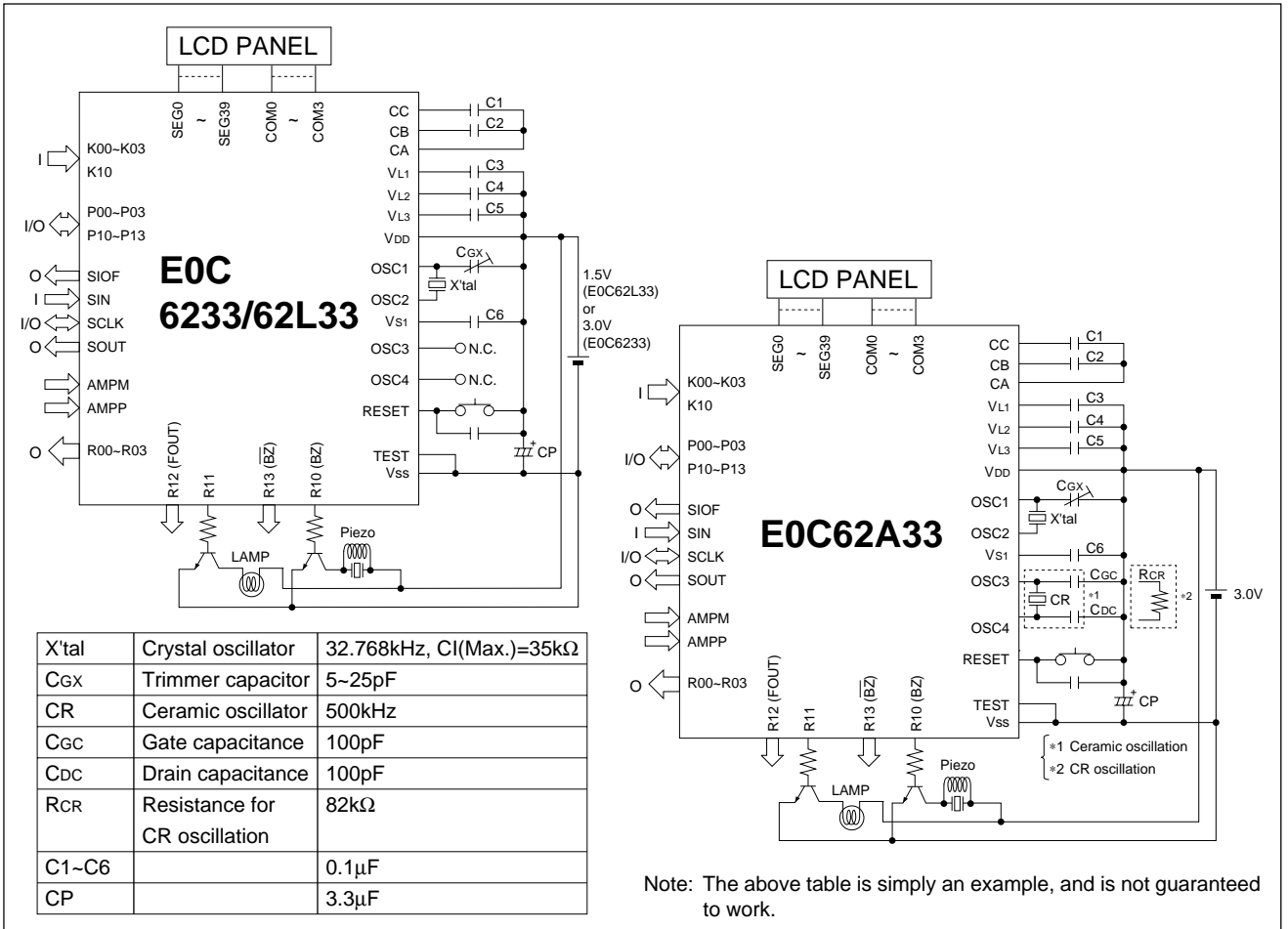
Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation frequency dispersion	fosc3		-30	430kHz	30	%
Oscillation start voltage	V _{sta}	(V _{SS})	-2.2			V
Oscillation start time	t _{sta}	V _{SS} =-2.2 to -3.5V			3	mS
Oscillation stop voltage	V _{stp}	(V _{SS})	-2.2			V

E0C62A33 (Ceramic oscillation circuit)

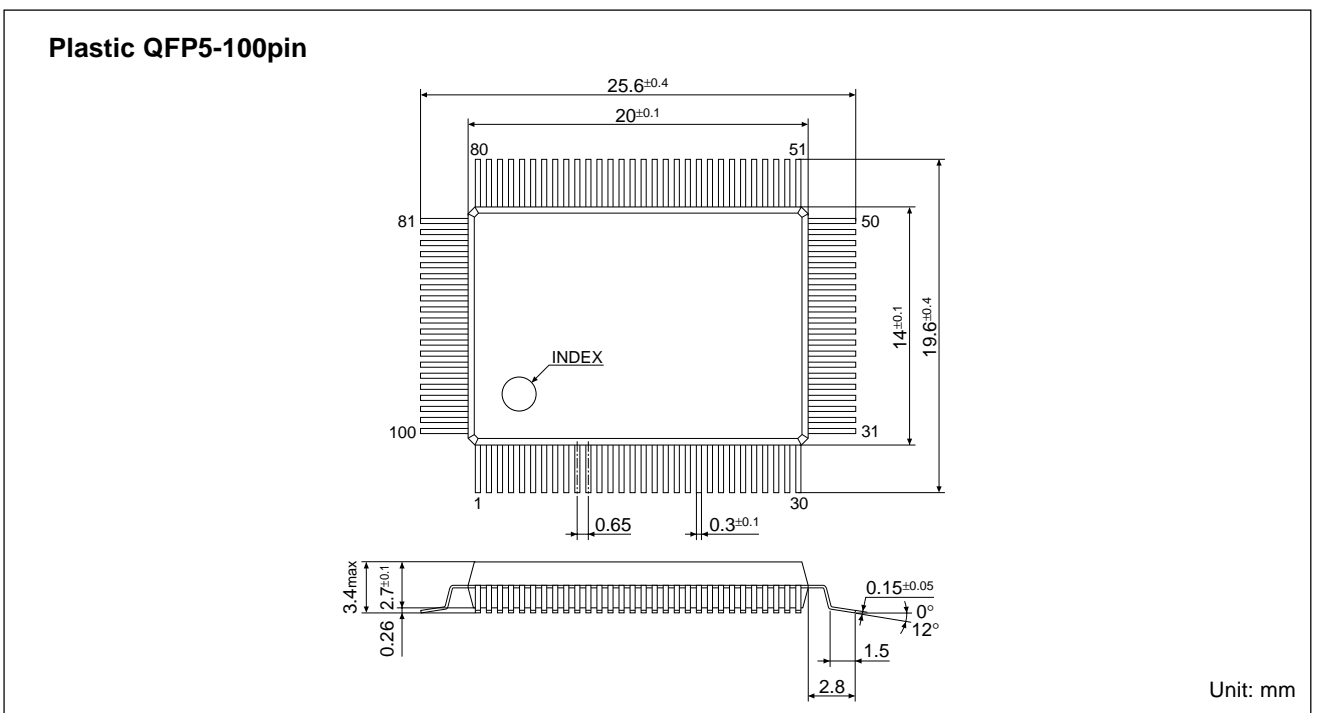
(Unless otherwise specified: V_{DD}=0V, V_{SS}=-3.0V, ceramic oscillation: 500kHz, C_{Gc}=C_{Dc}=100pF, T_a=25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation start voltage	V _{sta}	(V _{SS})	-2.2			V
Oscillation start time	t _{sta}	V _{SS} =-2.2 to -3.5V			5	mS
Oscillation stop voltage	V _{stp}	(V _{SS})	-2.2			V

■ BASIC EXTERNAL CONNECTION DIAGRAM



■ PACKAGE DIMENSIONS



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